## FAIRCHILD

SEMICONDUCTOR TM

## BD241/A/B/C

# Medium Power Linear and Switching Applications

Complement to BD242/A/B/C respectively



1.Base 2.Collector 3.Emitter

## NPN Epitaxial Silicon Transistor

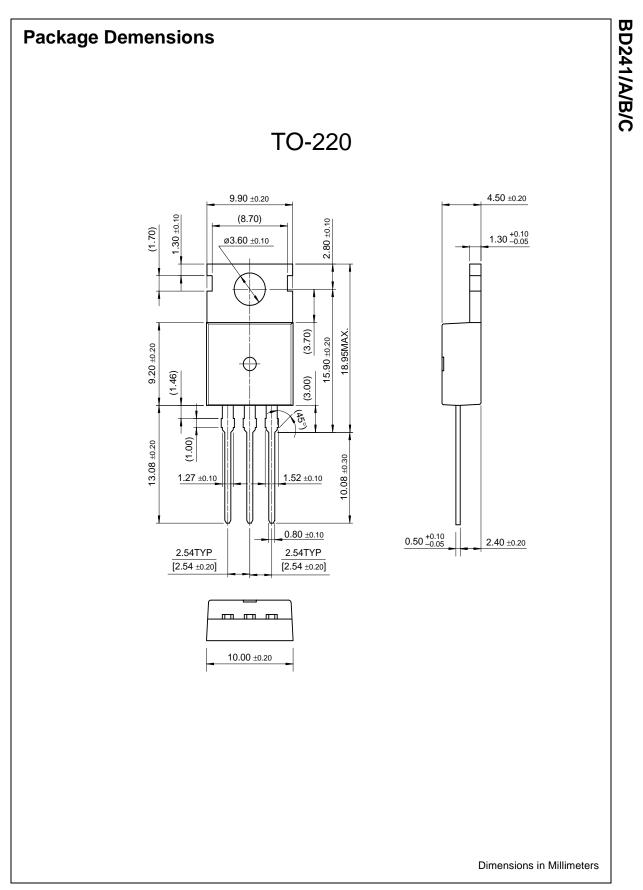
Absolute Maximum Ratings T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage		
	: BD241	45	V
	: BD241A	60	V
	: BD241B	80	V
	: BD241C	100	V
V <sub>CER</sub>	Collector-Emitter Voltage		
	: BD241	55	V
	: BD241A	70	V
	: BD241B	90	V
	: BD241C	115	V
V <sub>EBO</sub>	Emitter-Base Voltage	5	V
I <sub>C</sub>	Collector Current (DC)	3	А
I <sub>CP</sub>	*Collector Current (Pulse)	5	А
I <sub>B</sub>	Base Current	1	А
P <sub>C</sub>	Collector Dissipation (T <sub>C</sub> =25°C)	40	W
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	- 65 ~ 150	°C

### Electrical Characteristics T<sub>C</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
V <sub>CEO</sub> (sus)	* Collector-Emitter Sustaining Voltage					
	: BD241	I <sub>C</sub> = - 30mA, I <sub>B</sub> = 0	45			V
	: BD241A	-	60			V
	: BD241B		80			V
	: BD241C		100			V
I <sub>CEO</sub>	Collector Cut-off Current : BD241/A	$V_{CE} = 30V, I_{B} = 0$			0.3	mA
	: BD241B/C	$V_{CE} = 60V, I_{B} = 0$			0.3	mA
I <sub>CES</sub>	Collector Cut-off Current : BD241	V <sub>CE</sub> = 45V, V <sub>BE</sub> = 0			0.2	mA
	: BD241A	$V_{CE} = 60V, V_{BE} = 0$			0.2	mA
	: BD241B	$V_{CE} = 80V, V_{BE} = 0$			0.2	mA
	: BD241C	$V_{CE} = 100V, V_{BE} = 0$			0.2	mA
I <sub>EBO</sub>	Emitter Cut-off Current	$V_{EB} = 5V, I_{C} = 0$			1	mA
h <sub>FE</sub>	* DC Current Gain	$V_{CE} = 4V, I_{C} = 1A$	25			
		$V_{CE} = 4V, I_{C} = 3A$	10			
V <sub>CE</sub> (sat)	* Collector-Emitter Saturation Voltage	I <sub>C</sub> = 3A, I <sub>B</sub> = 0.6A			1.2	V
V <sub>BE</sub> (on)	* Base-Emitter ON Voltage	$V_{CE} = 4V, I_{C} = 3A$			1.8	V

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